



**Features** 

#### **60V N-CHANNEL ENHANCEMENT MODE MOSFET** PowerDI5060-8

100% Unclamped Inductive Switching (UIS) Test in Production -

manufactured in IATF 16949 certified facilities), please contact

Ensures More Reliable and Robust End Application Thermally Efficient Package - Cooler Running Applications

<1.1mm Package Profile - Ideal for Thin Applications Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and

Low RDS(ON) - Minimizes On-State Losses

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> Tc = +25°C	
60V	$15m\Omega @ V_{GS} = 10V$	32A	
60 V	$24m\Omega$ @ V <sub>GS</sub> = 4.5V	24A	

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and maintain superior switching performance, making it ideal for high

- Load Switch
- Adaptor Switch
- Notebook PC

efficiency power management applications.

# **Mechanical Data**

Case: PowerDI5060-8

High Conversion Efficiency

Low Input Capacitance Fast Switching Speed

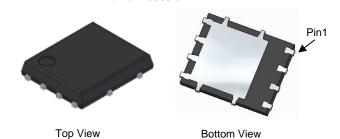
Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0

https://www.diodes.com/quality/product-definitions/

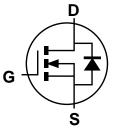
Moisture Sensitivity: Level 1 per J-STD-020

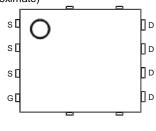
us or your local Diodes representative.

- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)



PowerDI5060-8





Top View Internal Schematic Pin Configuration

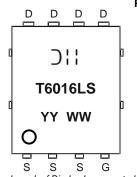
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging	
DMT6016LPS-13	PowerDI5060-8	2,500/Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## Marking Information



### PowerDI5060-8

The Manufacturer's Marking T6016LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.

DMT6016LPS Document number: DS37218 Rev. 7 - 2



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#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$		lD	32 25	А	
IIContinuous Drain Current (Note 5) Vos = 10V		$T_A = +25$ °C $T_A = +70$ °C	lο	10 8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDМ	120	Α
Maximum Continuous Body Diode Forward Current (Note 6)			Is	27	Α
Avalanche Current (Note 7) L = 0.1mH			I <sub>AS</sub>	15.3	Α
Avalanche Energy (Note 7) L = 0.1mH			Eas	11.7	mJ

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)  Steady State		$R_{\theta JA}$	49	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		P <sub>D</sub>	26	W
Thermal Resistance, Junction to Case (Note 6)	R <sub>θ</sub> JC	4.8	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

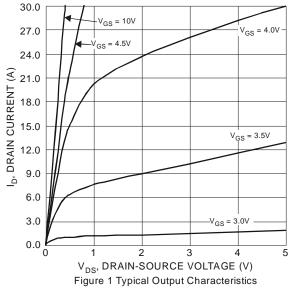
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

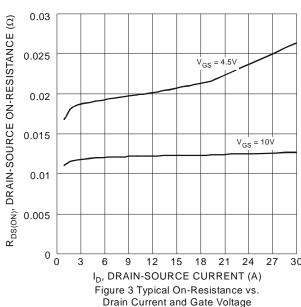
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	V <sub>DS</sub> =48V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	1	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D	_	_	15	mΩ	Vgs = 10V, ID = 20A	
Static Diain-Source On-Resistance	Rds(on)	_	_	24	11122	$V_{GS} = 4.5V, I_D = 18A$	
Diode Forward Voltage	VsD	_	0.7	1.2	V	Vgs = 0V, Is = 1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	864	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	_	282	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	27	_			
Gate Resistance	Rg	_	1.3	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	8.4	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	17	_	1		
Gate-Source Charge	Qgs	_	3.1	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 10A	
Gate-Drain Charge	Q <sub>gd</sub>	_	4.3	_			
Turn-On Delay Time	td(ON)	_	3.4	_			
Turn-On Rise Time	tR	_	5.2	_		Vgs = 10V, Vps = 30V,	
Turn-Off Delay Time	tD(OFF)	_	13	_	ns	$R_G = 6\Omega$ , $I_D = 10A$	
Turn-Off Fall Time	tF		7	_			
Reverse Recovery Time	t <sub>RR</sub>	_	22	_	ns	404 11/11 4004/	
Reverse Recovery Charge	Qrr	_	11	_	nC	-I <sub>F</sub> = 10A, di/dt = 100A/μs	

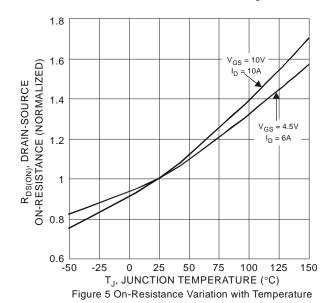
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:

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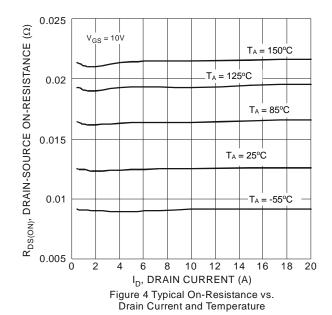








30 V<sub>DS</sub> = 5.0V 27 24 ID, DRAIN CURRENT (A) 21 18 15 12 9  $T_A = 150^{\circ}C$  $-T_A = 85^{\circ}C$ 6 T<sub>A</sub> = 125°C  $T_A = 25^{\circ}C$ 3 Γ<sub>A</sub> = -55°C 0 \_ 2 2.5 3 3.5 4 4. V<sub>GS</sub>, GATE-SOURCE VOLTAGE (V) 4.5 5 Figure 2 Typical Transfer Characteristics



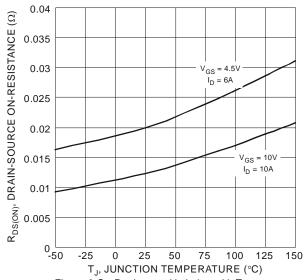


Figure 6 On-Resistance Variation with Temperature



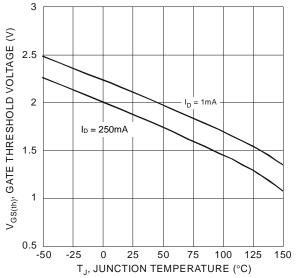


Figure 7 Gate Threshold Variation vs. Junction Temperature

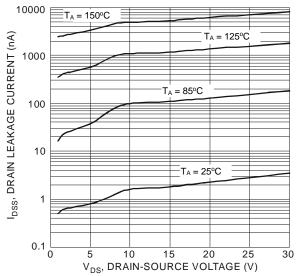
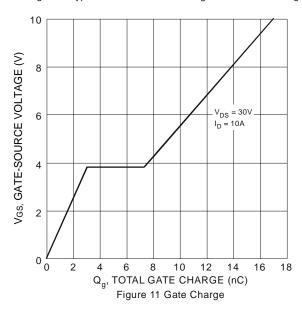
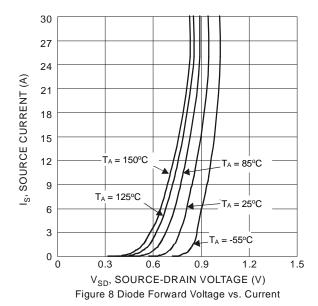
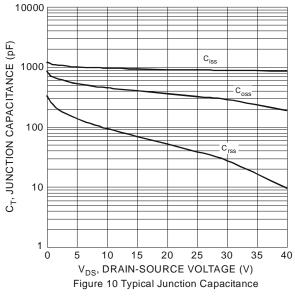
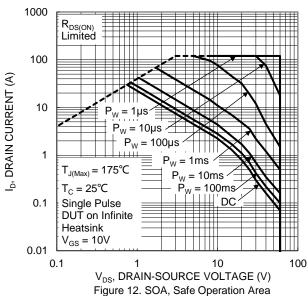


Figure 9 Typical Drain-Source Leakage Current vs. Voltage











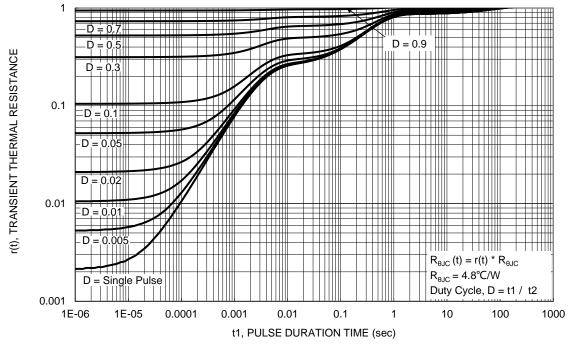


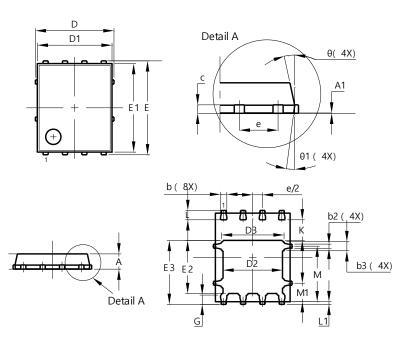
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

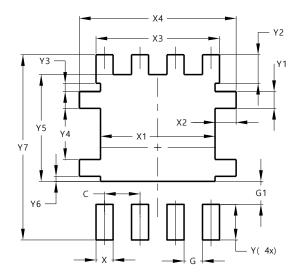


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
<b>A</b> 1	0.00	0.05			
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	;	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(	6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51				
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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